

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	66	((satura\$4 near3 (region or reflect\$4 or mirror or absorb\$4)) or sam) same ((arsenic or beryllium or proton\$2) same ion))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 08:34
L2	13	((satura\$4 near3 (region or reflect\$4 or mirror or absorb\$4))) same ((arsenic or beryllium or proton\$2) same ion))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 09:11
L3	58	((satura\$4 near3 (region or reflect\$4 or mirror or absorb\$4)) same (arsenic or beryllium or proton\$2))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:09
L4	2	((satura\$4 near3 (region or reflect\$4 or mirror or absorb\$4)) same (arsenic or beryllium or proton\$2) same energy)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 09:12
L5	3006	((satura\$4 near3 (region or reflect\$4 or mirror or absorb\$4)) same (Be or As or arsenic or beryllium or proton\$2))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:09
L6	1040	((satura\$4 near3 (mirror or absorb\$4)) same (Be or As or arsenic or beryllium or proton\$2))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:10
L8	48	((satura\$4 near3 (mirror or absorb\$4)) same (Be or As or arsenic or beryllium or proton\$2)) same ion)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:10
L12	1	((saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) or sam) and (passive with (modelock\$ or (mode near2 lock\$3))) and ((proton or arsenic or beryllium or beryl\$1ium) near3 implant\$4)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:14
L13	1	((saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) or sam) and (passive with (modelock\$ or (mode near2 lock\$3))) and ((proton or arsenic or beryllium or beryl\$1ium) SAME implant\$4)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:14
L14	1	((saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) or sam) and (passive with (modelock\$ or (mode near2 lock\$3))) and ((proton or arsenic or beryllium or beryl\$1ium) and (ion near4 implant\$4))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:14
L15	4	((saturab\$4 near3 (reflect\$4 or mirror or absorb\$4))) and ((proton or arsenic or beryllium or beryl\$1ium) and (ion near4 implant\$4))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:35
L16	2	((saturab\$4 near3 (reflect\$4 or mirror or absorb\$4))) and ((proton or arsenic or beryllium or beryl\$1ium) SAME (ion near4 implant\$4))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:21

L17	29	((saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) SAME (anti near2 reflect\$3))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:25
L18	1	(saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) and ((semiconductor near3 material) same (mult\$4 or plural\$4 or more) near3 relax\$5)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:53
L19	3	(saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) and ((semiconductor near3 material) and (mult\$4 or plural\$4 or more) near3 relax\$5)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:27
L20	1	(saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) and ((semiconductor near3 material) same (mult\$4 or plural\$4 or more) same relax\$5)	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:26
L21	4	((saturab\$4 near3 (reflect\$4 or mirror or absorb\$4))) and ((proton or arsenic or beryllium or beryl\$1ium) and (ion near4 (implant\$4 or introduct\$4)))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:36
L22	1	(saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) and ((semiconductor near3 material) same (mult\$4 or plural\$4 or more) near3 (nonstress or ease or loosen or unband or un lax or unwind or un stress or free or relax\$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 10:57
L23	2	(saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) and ((semiconductor near3 (material or element or film)) same (mult\$4 or plural\$4 or more) near3 (nonstress or ease or loosen or unband or un lax or unwind or un stress or free or relax\$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 11:06
L24	31	(saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) and ((semiconductor near3 (material or element or film)) same (nonstress or ease or loosen or unband or un lax or unwind or un stress or free or relax\$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 11:05
L25	13	(saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) and ((semiconductor near3 (material or element or film)) same (nonstress or ease or loosen or unband or un lax or unwind or un stress or relax\$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 11:05
L26	13	(saturab\$4 near3 (reflect\$4 or mirror or absorb\$4)) and ((semiconductor near3 (material or element or film)) same (nonstress or loosen or unband or un lax or unwind or un stress or relax\$5))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2005/07/26 11:10